

PC827/PC847

* Lead forming type (I type) and taping reel type (P type) are also available.
** TÜV (VDE0884) approved type is also available as an option.

■ Features

1. Current transfer ratio (CTR:MIN. 50% at $I_F=5\text{mA}$, $V_{CE}=5\text{V}$)
2. High isolation voltage between input and output ($V_{iso}(\text{rms})$:5kV)
3. Compact dual-in-line package
PC827:2-channel type
PC847:4-channel type
4. Recognized by UL, file No. E64380

■ Applications

1. OA equipment
2. Copiers
3. Home appliances

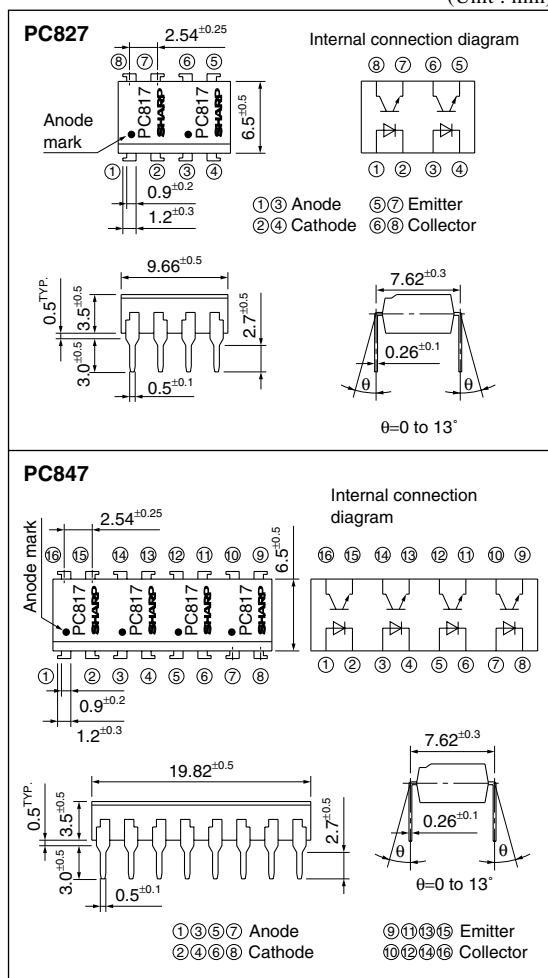
■ Absolute Maximum Ratings (T_a=25°C)

Parameter	Symbol	Rating	Unit
Input	Forward current	I _F	50 mA
	*1 Peak forward current	I _{FM}	1 A
	Reverse voltage	V _R	6 V
	Power dissipation	P	70 mW
Output	Collector-emitter voltage	V _{CEO}	35 V
	Emitter-collector voltage	V _{ECO}	6 V
	Collector current	I _C	50 mA
	Collector power dissipation	P _C	150 mW
	Total power dissipation	P _{tot}	200 mW
	*2 Isolation voltage	V _{iso} (rms)	5 kV
	Operating temperature	T _{opr}	-30 to +100 °C
	Storage temperature	T _{stg}	-55 to +125 °C
*3 Soldering temperature	T _{sol}	260	°C
	*1 Pulse width≤100μs, Duty ratio:0.001		
	*2 40 to 60%RH, AC for 1 minute		
*3 For 10s			

High Density Mounting Type Photocoupler

■ Outline Dimensions

(Unit : mm)



■ Electro-optical Characteristics(T_a=25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F =20mA	—	1.2	1.4	V
	Peak forward voltage	V _{FM}	I _{FM} =0.5V	—	—	3.0	V
	Reverse current	I _R	V _R =4V	—	—	10	μA
	Terminal capacitance	C _t	V=0, f=1kHz	—	30	250	pF
Output	Collector dark current	I _{CEO}	V _{CE} =20V, I _F =0	—	—	100	nA
Transfer characteristics	Collector current	I _C	I _F =5mA, V _{CE} =5V	2.5	—	30.0	mA
	Collector-emitter saturation voltage	V _{CE} (sat)	I _F =20mA, I _C =1mA	—	0.1	0.2	V
	Isolation resistance	R _{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	10 ¹¹	—	Ω
	Floating capacitance	C _f	V=0, f=1MHz	—	0.6	1.0	pF
	Cut-off frequency	f _c	V _{CE} =5V, I _C =2mA, R _L =100Ω, -3dB	—	80	—	kHz
	Response time	t _r	V _{CE} =2V, I _C =2mA, R _L =100Ω	—	4	18	μs
	Fall time	t _f		—	3	18	μs

■ Rank Table(I_F=5mA, V_{CE}=5V, T_a=25°C)

Model No.	Rank mark	I _C (mA)
PC8*7AB	A or B	4.0 to 13.0
PC8*7BC	B or C	6.5 to 20.0
PC8*7CD	C or D	10.0 to 30.0
PC8*7AC	A, B or C	4.0 to 20.0
PC8*7BD	B, C or D	6.5 to 30.0
PC8*7AD	A, B, C or D	4.0 to 30.0
PC8*7	A, B, C, D or no mark	2.5 to 30.0

*:2 or 4

Fig.1 Forward Current vs. Ambient Temperature

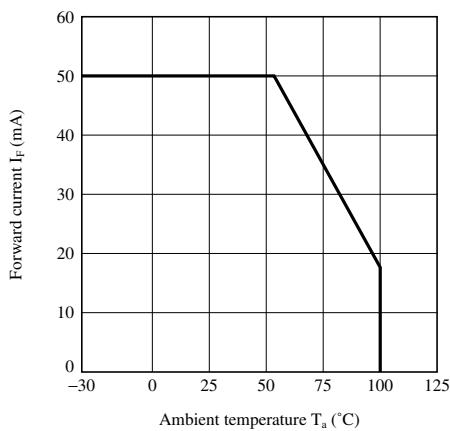


Fig.2 Collector Power Dissipation vs. Ambient Temperature

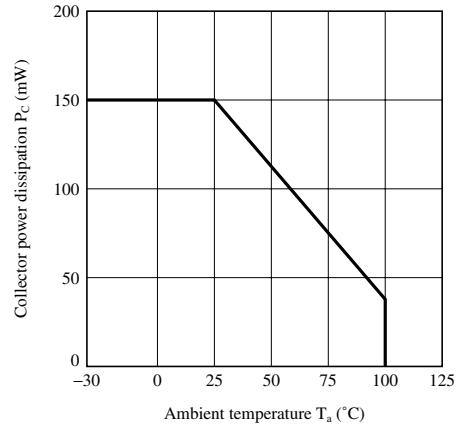


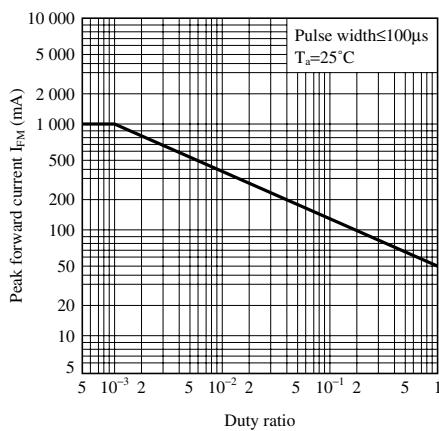
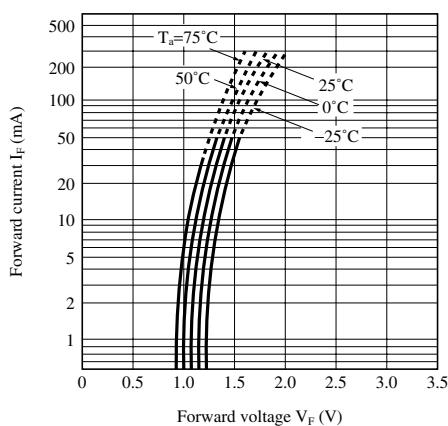
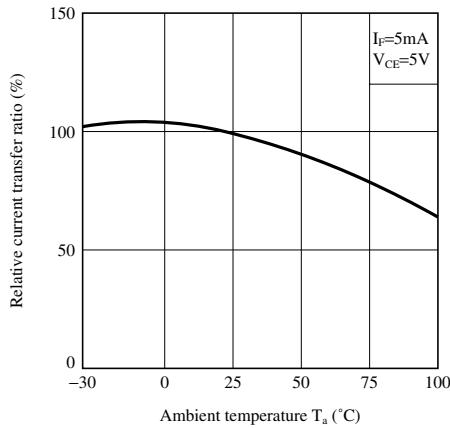
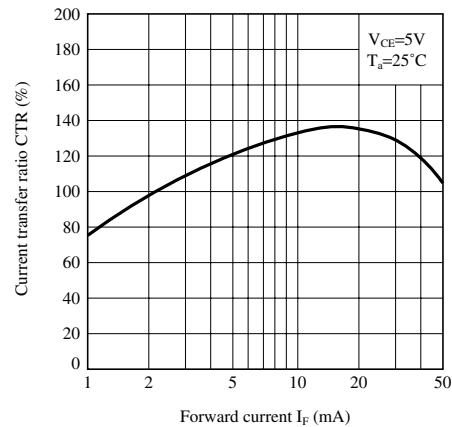
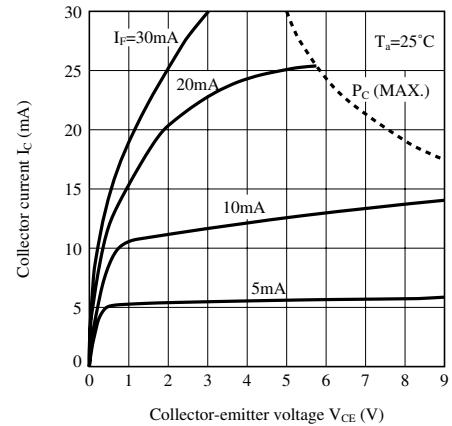
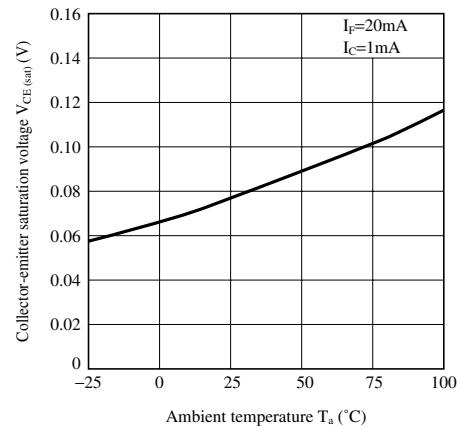
Fig.3 Peak Forward Current vs. Duty Ratio**Fig.5 Forward Current vs. Forward Voltage****Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature****Fig.4 Current Transfer Ratio vs. Forward Current****Fig.6 Collector Current vs. Collector-emitter Voltage****Fig.8 Collector - emitter Saturation Voltage vs. Ambient Temperature**

Fig.9 Collector Dark Current vs. Ambient Temperature

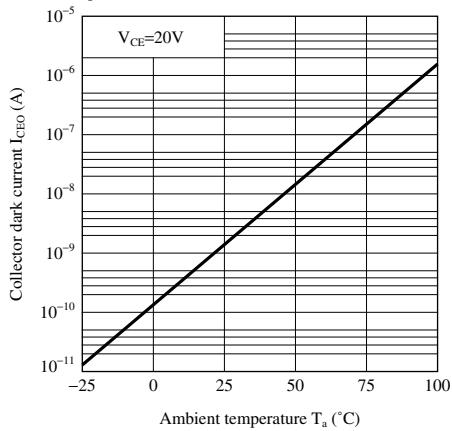


Fig.11 Response Time vs. Load Resistance

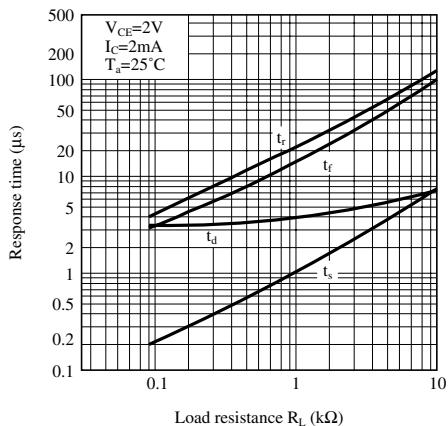


Fig.12 Frequency Response

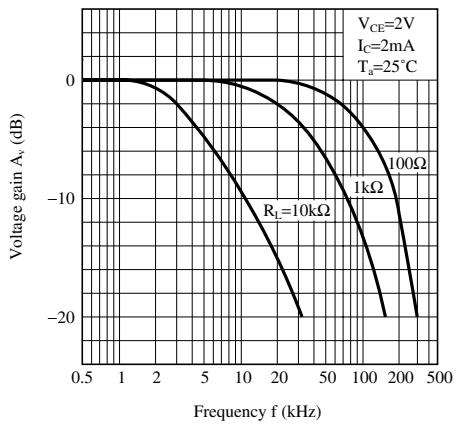
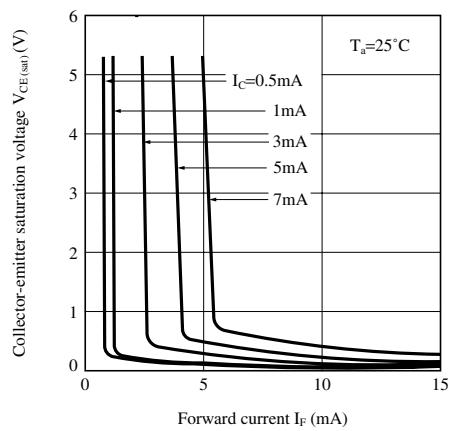
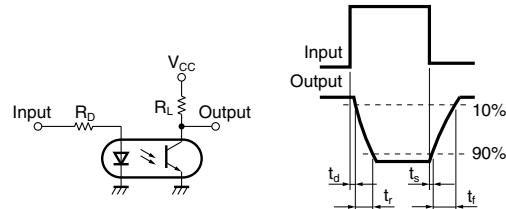


Fig.10 Collector-emitter Saturation Voltage vs. Forward Current



Test Circuit for Response Time



Test Circuit for Frequency Response

